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(54) Measuring and detecting printed circuit wiring defects.

(57) A non-contact system for detecting printed circuit wiring defects and for measuring circuit feature height relative to a substrate. The system has an energy source (32) for illuminating at an angle the substrate (30) and circuit features (31) and a scanner (36, 38) for both instantaneously receiving energy reflected from the substrate and circuit features and for generating a plurality of signals in response to the reflected energy, which signals are adapted to vary with the intensities of the locally reflected energies. An analyzer is connected to the scanner for correlating the generated signals to a measurement representative of the height of the circuit features relative to the substrate. Variations and non-uniformity of the substrate surface due to bending, warpage or other causes can be accounted for so as to provide an accurate measurement of the height of a circuit feature relative to the substrate surface on which it is mounted.

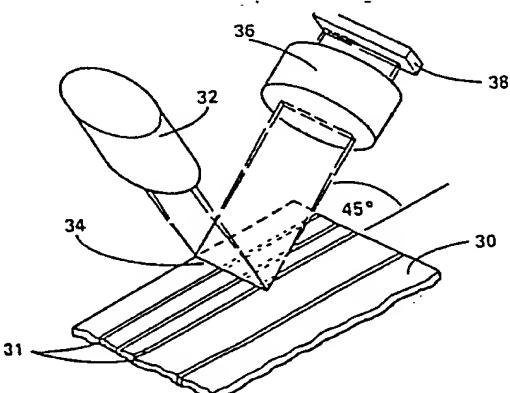


FIGURE 2

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Background of the Invention

The present invention relates to a system for measuring the height of circuit features on a substrate and more particularly to a non-contact system for detecting and measuring electrical conductor defects on a 5 printed circuit board.

Inspecting manufactured articles for defects and for proper placement in larger assemblies is often a time-consuming, yet necessary step in the production of complex devices. In the field of electronic components, inspection and measuring systems have relied on human inspectors using 10 microscopes or other more sophisticated equipment.

Such systems are, of course, labor intensive and prone to human operator error, being dependent upon eyesight and judgment. Moreover, in the course of inspecting and measuring components a potential exists for damaging the articles themselves, due to physical handling thereof. In fact, in certain 15 procedures for determining the integrity of wiring fabrication, so called destructive testing is undertaken on samples. If a sample fabricated at the same time and in the same manner as the manufactured product passes such a destructive testing procedure, it is assumed that the product itself is defect free. This assumption may be unwarranted in some cases.

20 A need has arisen for a procedure to inspect articles quickly, minimizing both manual labor and the possibility of damage to the articles during the inspection process, while increasing accuracy of the inspection. In particular, a non-contact procedure is preferred for inspecting and measuring the size and orientation of components as well as for detecting 25 wiring defects, if any, on a printed circuit board.

Dimensions of electronic components and thickness of wires or leads continue to decrease. Concomitantly, the criticality of positions of components and wires relative to the board or substrate on which they are mounted continues to increase. Accordingly, inspection procedures must be 30 increasingly accurate.

It can be appreciated that even relatively small defects in wiring become a greater problem as the size of the wire decreases. In previous systems

in which wiring dimensions were relatively great, small defects therein did not significantly affect performance of the overall system. With the ever decreasing size of wires used in sophisticated computing system sub-assemblies, however, relatively minor defects can result in performance degradation. Thus, defects that may not have even been detected in previous inspection systems must now be detected and corrected to ensure proper operation of the manufactured assemblies.

A system for measuring the two-dimensional size of geometrical features and/or their locations is described in "Noncontact Test System", by 10 S.H. Campbell, et al, IBM Technical Disclosure Bulletin, Vol. 14, No. 12, May 1972, p. 3621. This system uses a CPU for analyzing data generated by a scanner. The scanner receives light reflected from an illuminating source.

A test system for measuring placement of circuit lines on a substrate is 15 described in European Patent application EP-A-85,868 for "Apparatus for Automatic Optical Property Testing". In that system, an optical scanning head comprises two arrangements of linear diode arrays positioned adjacent one another. One diode array receives light reflected from a base plate while the other diode array receives light reflected from the surface of a 20 conductor, provided that the latter is at the desired nominal height. Detected defects are marked and may be displayed on a TV screen.

Light has also been used heretofore to detect defects in certain goods by responding to non-uniformities in light reflectance therefrom. U.S. Patent No. 3,712,466, issued to Aubry, et al, for example, teaches a system for 25 optically inspecting shell casings which are conveyed successively over a predetermined path. A photocell and lens system detects reflected light from the shell and determines, by non-uniformity in the reflected light level, whether a flaw or defect exists.

U.S. Patent No. 4,339,664, issued to Wiklund, et al, teaches a method and 30 apparatus for topographic measurements of a charged mass in a blast furnace. A distance meter is provided near the top of the furnace for detecting direct reflection against the upper surface of the charge. The distance meter has an aiming device so that measurements of selected parts of the surface can be measured.

Devices have also been used heretofore to measure the height of an object or target relative to a reference surface. Such devices are often used in radar systems. Visible light may also be used to measure the distance between such a target and a surface. U.S. Patent No. 3,669,540, issued to 5 Rattman, et al, for example, discloses one such system in which a laser on board a helicopter is used to measure the depth of the ocean or of a submerged object. In this aforementioned reference, the altitude of the helicopter is determined by measuring the time interval between the transmission of a laser pulse and the detection of the resulting energy 10 reflected from the ocean surface. The time interval between the transmitted laser pulse and the detected reflected energy from the surface of the ocean is compared to the time interval between the transmitted laser pulse and the detected reflected energy from the ocean floor or submerged object in order to arrive at the relative depth thereof. Such a system requires 15 accurate time measurement, using the speed of light as a factor.

Systems have also been disclosed for use with considerably more complex light detecting apparatus. For example, U.S. Patent No. 4,349,277, issued to Mundy, et al, discloses a parallax system for measuring and mapping a surface profile in which a light beam is split into two beams, each having 20 a different frequency. Two images are projected onto a color pattern and a shift in the relative distance between the pattern and the light source can be detected, indicating roughness variations.

U.S. Patent No. 4,017,188, issued to Sawatari, discloses an optical system for determining surface roughness which includes two light detectors that 25 view two separate images of a spot focused by a lens through a slit. The respective detector signals are divided to produce signals corresponding to the ratio thereof, which in turn correspond to variations of surface height occurring as the illuminated spot is scanned across the surface.

Similarly, U.S. Patent No. 3,713,739, issued to Zarezankov, et al, 30 discloses a system in which a beam of light strikes each of the opposite surfaces of a rolled product, producing an image onto two separate screens of electron beam tubes. The distance between the images is measured and used to derive the distance of linear cross-sectional dimensions of the rolled product.

It would be advantageous to provide an optical non-contact system for measuring the height of circuit features on a substrate without the need for complex optical or time measurement apparatus.

It would also be advantageous to provide a system for three-dimensional 5 optical measurement with the use of only one imaging device capable of distinguishing substrate energy reflectance from circuit feature energy reflectance.

It would further be advantageous to perform such measurement independent of light reflection time and/or substantially instantaneously.

10 It would also be advantageous to measure the height of such circuit features relative to a substantially planar but non-uniform substrate on which they are mounted.

It would also be advantageous to use the level of intensity of reflected light both to determine the height of circuit features and to detect and 15 compensate for non-linearities in the upper surface of the substrate on which they are mounted.

Summary of the Invention

In accordance with the present invention, as claimed, there is provided a non-contact system for detecting printed circuit wiring defects and for 20 measuring circuit feature height relative to a substrate. The system has an energy source for illuminating the substrate and circuit features and a scanner for both instantaneously receiving energy reflected from the substrate and circuit features and for generating a signal in response to the reflected energy, which signal is adapted to vary with the intensity 25 of the reflected energy. An analyzer is connected to the scanner for correlating the generated signal to a measurement representative of the height of the circuit features relative to the substrate.

Moreover, variations and non-uniformity of the substrate surface due to bending, warpage or other causes can be accounted for so as to provide an 30 accurate measurement of the height of a circuit feature relative to the substrate surface on which it is mounted.

Brief Description of the Drawings

A complete understanding of the present invention may be obtained by reference to the accompanying drawings, when taken in conjunction with the detailed description thereof and in which:

5 FIG. 1 is an exploded perspective view of a portion of three additively plated circuit wires with defects therein;

FIG. 2 is a perspective view of a light slit projected onto a circuit board and circuit features;

FIG. 3 is a perspective view of a light slit projected onto a circuit feature;

FIG. 4 is a top plan view of a light slit projected onto a circuit feature;

FIG. 5 is a perspective view of a circuit feature having a defect therein;

FIG. 6 is a top plan view of a light slit projected onto a circuit feature having a defect therein;

FIG. 7 is a cross-sectional view of a portion of a non-uniform printed circuit board;

FIG. 8 is a graphical piece-wise analysis of the substrate base and circuit feature height on a non-uniform circuit board;

?0 FIG. 9 is a block diagram of the detecting and measuring system in accordance with the present invention; and

FIG. 10 is a flow chart of the inventive process for use with the detection and measuring system in accordance with the present invention.

Detailed Description of the Preferred Embodiment

Referring now to FIG. 1, there is shown a greatly enlarged and exploded perspective view of three circuit features, such as electrically conductive wires fabricated by an additive plating process, such as is described in 5 U.S. Patent Nos. 3,844,799 issued to Underkofler, et al and 4,152,467 issued to Alpaugh, et al. It should be understood, however, that the product of any other type of additive process or any other circuit fabrication process may be prone to the defects described herein, all of which are detectable and measurable by the present invention.

10 The circuit features shown in FIG. 1 have three-dimensional defects therein. Circuit feature 10 includes a base material 12 such as copper, which is normally bonded to a substrate, not shown, and then appropriately etched. During an additive plating process, more material 14 is then deposited onto the etched base layer 12. The added material 14 is 15 electrically conductive, such as copper in the preferred embodiment. Occasionally during the printed circuit fabrication process, an irregularly shaped three-dimensional defect 16 may occur due to any one of a number of causes well known in the art of additive plating, for example. The defect identified by reference numeral 16 is commonly referred to as 20 "dish down".

As another example of defects, circuit feature 18 is also mounted on a base material 12 and has a pair of defects 20a and 20b commonly known as "neck down". Finally, circuit feature 22, mounted on a base material 12, has a defect 24 commonly known as "plating void" or "pinhole".

25 It should be understood that while the aforementioned defects occur most commonly, other types of defects, such as nodules formed from excess copper and the like, may also be formed during an additive process. The present invention is intended to detect and measure any such defects, however formed.

30 Referring to FIG. 2, there is shown a substrate 30, such as a printed circuit board, on which are placed or formed circuit features 31 such as lines of electrical conductance. These circuit features 31 may be embedded in or laminated onto the printed circuit board 30. The circuit features 31 may have defects, not shown in FIG. 2, as hereinabove described, which are

detectable and measurable by the present invention.

A slit of light is generated by a light source, not shown, through a suitable optical lens assembly 32. The optical lens assembly 32 may be a multiple element lens or a series of lenses as are commonly used and well known in the art. In the preferred embodiment, cylindrical optics 32 are used to project a slit of light 34 approximately 12.5 μm wide and 28 mm long. The light slit 34 in the preferred embodiment is projected onto the printed circuit board 30 such that the angle of incidence is 45° relative to the plane thereof in order to provide light which represents the true proportion of features measured along the height dimension. It should be understood, however, that an angle less than or greater than 45° may be used to optimize contrast as well as to satisfy other design considerations.

A collector lens 36 is disposed opposite the light lens 32 for receiving reflected light from the printed circuit board 30 also at an angle of 45° relative to the plane thereof. Optically related to the collector lens 36 is a charge coupled device (CCD) 38 or imaging device, such as is manufactured by Fairchild Camera and Instrument Corp. as Model No. 1600R, for receiving the image of the slit 34 projected onto the board 30 and reflected therefrom.

The board 30 is adapted to move in directions parallel to the plane thereof (i.e., in the X and Y directions) relative to the light source and optical lens 32 by suitable means. It will be appreciated, however, that the board 30 may be stationary while the lens 32 is passed thereover. Similarly, although one CCD 38 is shown in FIG. 2, it should be understood that the system may be adapted for use with an array of light detecting devices, such as CCD's or the like. The array of CCD's may be polled so that each CCD device is individually accessed and the data therefrom is appropriately organized in a format that is usable in future analysis.

Referring now also to FIG. 3, there is shown an exploded perspective view of an electrical conductor 50 and base 51 plated onto a substrate 52. A light slit 54 is projected onto the substrate 52. The portion of the light slit 54 that is interrupted by the upper surface of the conductor 50 is identified by reference numeral 56.

Referring also to FIG. 4, there is shown a top view of the light slit 54 projected onto both the electrical conductor 50 and the substrate 52. When the light slit 54 is projected at an angle of 45° relative to the plane of the printed circuit board substrate 52 as shown in FIG. 2, the distance X 5 between the light slit 56 projected onto the conductor 50 and the light slit 54 projected onto the substrate 52 is equal to the height of the conductor 50 relative thereto.

Referring to FIG. 5, there is shown another electrical conductor circuit feature 60 and its base 61 in which an irregularly shaped defect 62 of the 10 dish down variety has occurred.

Referring now also to FIG. 6, there is shown a top plan view of a light slit 64 projected onto a substrate 65 on which is located the circuit feature 60. The light slit on the top surface of the circuit feature 60 is identified by reference numeral 66. The portion of the defect 62 onto 15 which the light slit 66 is projected is identified by reference numeral 68.

Referring to FIG. 7, there is shown a cross-sectional view of a printed circuit board 70 with circuit features 74 and 76 located thereon. The circuit board 70 has an upper surface 72 which is warped along the Z-axis (vertical dimension). That is, the upper surface 72 of the printed circuit 20 board 70 is higher on one side 78 than it is on the other side 79.

Circuit features 74 and 76 both have equal dimensions in the Z direction, but are situated on the substrate 70 so that the overall height of circuit feature 74 measured from an initial reference level I is greater than the overall height of circuit feature 76, measured from initial level I. Thus, 25 it can be seen that to determine the height dimension of each circuit feature 74 and 76, the height of the upper surface of the substrate at reference numerals 78 and 79 proximate the base of respective circuit features 74 and 76 must also be determined and subtracted from the overall measurements of circuit feature upper surface, all relative to initial 30 level I.

Referring now also to FIG. 8, there is shown a graphical representation of substrate height and height of a circuit feature over a horizontal distance on an uneven or non-uniform substrate 30. Line 80 is a profile of the upper surface of the substrate 30. Line 82 represents the topmost

surface of the circuit feature 31. All height measurements are taken relative to the initial reference level I.

The graph in FIG. 8 is generated by taking 25 mm long height slices along the area to be measured. In the preferred embodiment, 12 slices (10 of 5 which are shown, vertically, in FIG. 8), separated from one another by a separation distance of $12.5 \mu\text{m}$, are required to bracket the distance from below the upper surface of the substrate 30 to above the upper surface of the circuit feature.

It should be appreciated, however, that arbitrary separation distances 10 between height slices other than $12.5 \mu\text{m}$ can be chosen in other situations, depending upon the size of the circuit features being measured as well as upon the degree of precision required. Moreover, the separation distances chosen need not be uniform in all situations. Similarly, the number of height slices used in other situations may vary according to prevailing 15 spatial and precision parameters.

In the example depicted in FIG. 8, light is not reflected from the substrate 30 at a height level of $0 \mu\text{m}$ or $12.5 \mu\text{m}$ relative to initial reference level I. This is to be expected, as initial level I is below the upper surface of the substrate 30 and the plane at that height is imaginary 20 as far as the image receiving CCD 38 is concerned. The image at initial level I is non-existent. Accordingly, neither the base line 80 nor the upper surface copper line 82 appears at $0 \mu\text{m}$ or $0.5 \times 25 \mu\text{m}$. At a height of $1.0 \times 25 \mu\text{m}$, however, the light slit 34 is reflected from the upper surface of the substrate 30 and registers on the CCD 38 in the leftmost 25 column of the graph.

As the height dimension is incrementally increased at $12.5 \mu\text{m}$ separation distance intervals, no additional reflectance is found until a height of $3.0 \times 25 \mu\text{m}$ is achieved. At this level, higher reflectance intensity indicates that copper is present $75 \mu\text{m}$ from the initial reference level I. 30 The relative height of the copper line is thus 3.0 minus 1.0 , or $2.0 \times 25 \mu\text{m}$.

As the optical system continues to scan the sample, the substrate 30 warps upwardly in this example to $1.5 \times 25 \mu\text{m}$, shown at reference numeral 84. The copper height is correspondingly displaced from the initial reference
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level I and measures 50 μm at all locations along the 25 mm long length of the light slit 34.

Referring now again to FIG. 2, when a light slit 34 is directed through the lens 32 to the substrate 30, the CCD 38 is adapted to receive the reflected light, as hereinabove described. The CCD 38 generates a signal that varies with the intensity of the light received.

Connected to the CCD 38 is an electrical circuit, not shown in FIG. 2, for analyzing the signal generated by the CCD 38 in response to the intensity of the reflected light. This circuit, described more fully hereinbelow, is capable of distinguishing the CCD signal and classifies it according to one of three conditions: that which represents a substantially zero level of reflectance; that which represents a relatively low reflectance level; and that which represents a relatively high level of reflectance.

Two threshold levels are required to separate the three aforementioned reflectance levels: the first threshold level separates the substantially zero reflectance level from the relatively low reflectance level, and the second threshold level separates the relatively low reflectance level from the relatively high reflectance level.

The first threshold represents reflectivity of the upper surface of the substrate 30 while the second threshold represents reflectivity of the upper surface of copper lines 31. Accordingly, reflectance intensity below the first threshold level indicates that the upper surface of the substrate 30 has not been reached by the light source/CCD 38 combination. Likewise, reflectance intensity higher than the first threshold level (but lower than the second threshold level) indicates that the light slit 34 is reflected by the upper surface of the substrate 30. Finally, reflectance intensity higher than the second threshold level indicates that the copper line reflects light slit 34.

The intensity of the reflected light beam is a function of the material that reflects it. Copper reflectivity is, of course, substantially greater than substrate reflectivity. By setting appropriate threshold levels, the upper surface of the substrate 30 and of the copper lines 31 can be detected and differentiated with respect to one another.

Correlating this identification of material with the height at which each threshold level is reached results in data that can be used in accurately determining the height of the copper lines 31 with respect to the upper surface of the substrate 30. Moreover, printed circuit wiring defects can 5 also be identified either by detecting reflected light at a height at which no reflection is expected or by failing to detect reflected light at a height at which reflection is expected.

Referring now to FIG. 9, there is shown a block diagram representation of the system in accordance with the present invention. A light source 100, 10 such as a laser supplied by the Lexel Co. as Model No. 65, is used for illumination. A laser is preferred because it emits a bright, concentrated light and it can be chosen to emit a light frequency optimally matched to the materials tested.

The optical lens assembly 32 forms the light slit 34, as hereinabove 15 described. Mounted in close proximity to the optical lens assembly 32 is an acousto optic modulator (AOM) 104, such as Model No. AOM-80 manufactured by Intraaction Co., which is an electro-optical device used to deflect the light slit 34.

A numerically controlled table 106 is provided to support a printed 20 circuit board 30 under test and to move the board 30 along both an X-axis and a Y-axis. The CCD imaging device 38 is provided to receive light reflected from the board 30 and to generate a signal in response to the image, the signal adapted to vary with the intensity of the reflected light.

25 A dynamic threshold electrical circuit 112 is connected to the CCD 38 and receives an electrical signal therefrom. The circuit 112 has two threshold levels, as hereinabove described. One threshold level represents substrate reflectivity and the other represents copper reflectivity. The threshold levels are also dynamic. That is, they are instantaneously adjustable to 30 account for differing reflectivity of the copper lines 31 on the same board 30. Such reflectivity variations may occur due to oxidation or due to other chemical or mechanical causes. A pre-selected analog voltage copper reflectivity level 114 is input to the dynamic threshold circuit 112. Similarly, an analog voltage substrate reflectivity level 116 is also 35 input to the dynamic threshold circuit 112.

Connected to the dynamic threshold circuit 112 is a 12-line compression buffer 118 containing 6K bytes of memory. The buffer 118 can store video information corresponding to a predetermined number of height slices for each single line of the final image. Typically ten to twelve 5 2048 x 1 pixel (i.e. picture element) height slices are stored in this buffer 118, but it should be understood that the size and use of this buffer 118 is a matter of design and can be adjusted according to individual system parameters and requirements.

Two bits of reflectance information per pixel are stored in the 12-line 10 buffer 118. The two bits of information are required in the preferred embodiment to represent each reflectance category uniquely for each pixel. In the preferred embodiment, a pixel having the lowest reflectance or intensity level is represented by the arbitrary binary value 00. The next higher reflectance level is represented by the binary value 01, and the 15 highest reflectance level is represented by the binary value 11. Of course, it should be understood that the number of bits required is dependent upon the number of threshold levels being analyzed which, in turn, depends upon the material under test. Different types of material, such as silver, platinum or gold, reflect different amounts of light. Similarly, different 20 conditions of one material (impurities, oxides and the like) also reflect different intensities of light. Thus, in certain systems more than two binary bits of information may be needed to differentiate and identify all required intensity levels of reflectance. The binary value scheme chosen for these bits may, of course, be arbitrarily set by those skilled in the 25 computer programming art.

Analysis circuitry 120 is used to compress height data into one line of data. The height slices are analyzed to determine copper line heights by dividing each slice into columns and counting the slices between the substrate 30 and the copper 31. To increase processing speed, Arithmetic 30 Logic Units (ALU's), such as are supplied by Texas Instruments as Model Number 74S181, can be incorporated in the analysis circuitry 120. Each ALU is used to perform arithmetic operations such as addition, subtraction and comparison to analyze one or more of the columns to determine copper height therein. The ALU's operate in parallel in the preferred embodiment 35 to increase throughput.

A multiplexer (MUX) 122 is connected to identical memory frame devices 124 and 126. The memory frame devices 124 and 126 each store a 2K x 2K video pixel image. A frame of video appears as an image of one square 25 mm of the tested substrate in the preferred embodiment. Each memory frame device 124 and 126 is a stand alone unit capable of storing and individually addressing the required 4,194,304 (2048 x 2048) pixels of information.

The pixel and reflectance data stored in the memory frame devices 124 and 126 is available for further analysis by a human inspector or by a computer operating under either a rules driven or a data driven procedure.

10 The memory frame devices 124 and 126 are connected to a CPU 130 such as any personal computer having direct memory access (DMA) 131 capability. The CPU 130 allows data stored in each memory frame device 124 and 126 to be unloaded therefrom sequentially.

15 A commercially available graphics display card 128, supplied by Control Systems Co. under the trademark ARTIST I, is connected to the CPU 130. The primary purpose of the graphics display is for diagnostic evaluation and development. It need not be used in the analysis of the image by a computer. The graphics display card 128, under CPU control, converts height information into a topographic representation much like a
20 topographic map. The differing height information can be represented by different colors. The colors are uniquely identified by combinations of 3 bits generated by the ALU's 120 and transferred to the multiplexer 122. Three bits of height information are capable of representing eight colors, each one corresponding to a unique height.

25 A signal output from the CPU 130 also operates the numerically controlled table 106 to move the board 30 along the X-axis, the Y-axis or both, as required.

30 A microprocessor 132, such as a Motorola Model No. 68000 16-bit micro-processor, is provided to control address lines input to the 12-line compression buffer 118 and to control one or more 8-bit microprocessors 134, such as Model No. 6809 connected thereto. The microprocessors 134 coordinate the activities of the ALU's 120 that perform piece-wise columnization to compress height data. The microprocessor 132 also controls the AOM 104 to deflect the light slit 34 (FIG. 2).

Referring now also to FIG. 10, there is shown a flow chart of the steps of the process used in carrying out the present invention.

In operation, the laser 100 generates a coherent beam of light through the optical lens assembly 32. The optical lens assembly 32 shapes this beam of 5 light into a slit which is directed through the AOM 104 to impinge on the circuit board 30 and the circuit features thereon. The CCD 38 is focused at a plane substantially parallel to the plane of the circuit board 30 and slightly below the upper surface thereof, step 200. A signal is generated by the CCD 38 in response to reflected light, if any, and applied to the 10 dynamic threshold circuit 112. The signal generated by the CCD 38 is input to the dynamic threshold circuit 112 on a piecemeal basis.

The dynamic threshold circuit 112 generates a signal dependent upon the signal received from the CCD 38. The dynamic threshold circuit 112 analyzes the input signal and determines: whether it is below the first 15 threshold (representing light reflected from the upper surface of the substrate 30); whether it is above the second threshold (representing light reflected from the upper surface of the circuit feature 31); or whether it is between the two aforementioned thresholds.

A binary value is assigned by the dynamic threshold circuit 112 to each 20 pixel data item, step 204. The binary values are then transferred from the threshold circuit 112 to the 12-line compression buffer 118 for storage therein, step 206.

A counter for the 12-line buffer 118 determines whether the height slice is complete (i.e., whether it contains 2048 pixel data items), step 207. 25 If the height slice is not complete, the CCD 38 again scans light reflected by the board 30, step 200.

The focal plane is then incremented, step 208, by modulating the AOM 104. The microprocessor 132 directs the AOM 104 to deflect the light slit 34 (FIG. 2) that impinges on the printed circuit board 30 and, in conjunction 30 with the CCD 38, focuses the light slit 34 along different planes parallel to the printed circuit board plane, incrementally raising the focused planes from the initial lowest plane (level 1) to the uppermost plane (level 12) which is well above the expected upper surface of the circuit feature 31.

The 12-line compression buffer 118 continues to be loaded. If the buffer 118 is not completely full, step 210, scanning operations continue, step 200. When all lines in the buffer 118 are loaded, step 210, the data from the buffer 118 is transferred to the ALU's 120 and compressed thereby into one 5 line of information, step 212.

The compressed lines of data are transferred to the multiplexer 122 and thence to one of the memory frame devices 124 or 126, step 214. The numerically controlled table 106 is incremented and repositioned under direction of the CPU 130, step 215. The first memory frame device 124 has 10 a capacity for 2048 compressed lines of data. If the memory frame device 124 is not full, step 216, scanning continues, step 200. When the first memory frame device 124 contains 2048 compressed lines of data, step 216, however, the data in that memory frame device 124 may be analyzed, step 218. Scanning then continues from step 200 and the system begins analysis of 15 the next set of twelve levels. Thus, over a period of time, the entire printed circuit board 30 is inspected for each of twelve plane levels.

As new pixel data items are received by the CCD 38, the threshold circuit 112 assigns binary values to each pixel data item and loads the 12-line compression buffer 118, which in turn supplies the data to the 20 ALU's 120 for compression. At this point, the microprocessor 132 generates a signal to the multiplexer 122, which switches between the first memory frame device 124 and the second memory frame device 126 when 2048 compressed lines of image data have been stored in the first memory frame device 124, step 222.

25 The second memory frame device 126 fills up in due course until 2048 compressed lines of data are stored therein, step 216. The multiplexer 122 then switches the ALU 120 output back to the first memory frame device 124, step 222. In this way, the multiplexer 122 loads memory frames 124 and 126 in ping pong fashion, thus increasing throughput of the system. While one 30 memory frame device 124 is being loaded with ALU compressed data, the data stored in the other memory frame device 126 can be accessed and analyzed by a separate image analysis system, not shown. The CPU 130 can DMA access either memory frame device 124 or 126 when that particular memory frame device is not being filled by data from the ALU's 120.

More than two memory frame devices may be used if the image analysis system operates at a significantly slower rate than the ALU/memory frame device subsystem. Similarly, only one memory frame device need be used if the image analysis system connected thereto operates on a FIFO or partial 5 memory access basis and responds quickly enough to be compatible with the ALU/memory frame device subsystem.

The microprocessor 132 also supplies address information correlated with the AOM 104 plane under analysis to the compression buffer 118. In this — way, the data from each plane level under analysis can be correlated with 10 the dynamic threshold circuit 112 and the threshold levels therein.

Since other modifications and changes varied to fit particular operating requirements and environments will be apparent to those skilled in the art, the invention is not considered limited to the example chosen for purposes of disclosure, and covers all changes and modifications which do 15 not constitute departures from the scope of this invention.

CLAIMS

1. A non-contact system for detecting printed circuit wiring defects and for measuring circuit feature (31, 50) height relative to a substrate (30, 52) characterized by:
 - a) an energy source (100, 32, 104) for locally illuminating (34, 54, 56) said substrate (30) and circuit features thereon at a predetermined angle of incidence;
 - b) scanning means (36, 38) disposed proximate said substrate and circuit features thereon and operatively related thereto, said scanning means being adapted for:
 - i) substantially instantaneously receiving energy reflected from said substrate and circuit features thereon; and
 - ii) generating a signal in response thereto, said signal being adapted to vary with the intensity of said reflected energy; and
 - c) analyzing means (112-118) operatively connected to said scanning means for correlating said signal received therefrom to a measurement representative of height of said circuit features on said substrate and relative thereto.
2. The system in accordance with claim 1 wherein said energy source is a laser and said scanning means is an electro-optical device.
3. The system in accordance with claim 2 wherein said energy source comprises cylindrical optics (32) to project a slit of light onto said substrate (30) and said electro-optical device (38) is a linear charge coupled device (linear CCD) having a plurality of elements disposed therein.
4. The system in accordance with claim 3 wherein said linear CCD receives energy reflected from a predetermined area (34, 54, 56) on said substrate and circuit features thereon and wherein said plurality of CCD elements are individually and simultaneously

activated.

5. The system in accordance with claim 4 wherein the energy received by each of said plurality of CCD elements is individually and independently analyzed for a predetermined number of cycles corresponding to different height levels relative to a base level (I) so that non-linearities on said substrate and circuit features thereon are detected.
6. The system in accordance with claim 1 further comprising:
 - d) positioning means (106) for moving said scanning means (32-38) relative to said substrate (30).
7. The system in accordance with claim 1 wherein said analyzing means comprises a first memory (118) for storing data representative of said signal generated by said scanning means, and
said analyzing means comprises a second memory (124, 126) for storing analyzed data representative of the height dimensions of said circuit features.
8. The system in accordance with claim 7 wherein said analyzing means further comprises means (120) for using said data stored in said first memory to calculate the height of said circuit features.
- 20 9. The system in accordance with claim 1 wherein said analyzing means (112) is adapted to detect three categories of reflected energy intensity, said categories being bounded and defined by two threshold levels (114, 116), where
one of said threshold levels separates the intensity of background energy from the intensity of energy reflected from said substrate, and
the other one of said threshold levels separates the intensity of energy reflected from said substrate from the intensity of energy reflected from said circuit features, whereby the presence of said circuit features is detected.

10. The system in accordance with claim 1 or 5 further comprising:

e) means (104) for moving said energy discretely through a plurality of focal planes over at least the field of view relative to said scanning means (38).

5 11. The system in accordance with claim 10 wherein said energy moving means is an acousto-optic modulating device.

12. A method for detecting printed circuit wiring defects and measuring the height of the upper surface of a circuit feature relative to a substrate upper surface, characterized by the steps of:

10 a) projecting energy locally at an angle onto said substrate and circuit feature thereon;

b) providing a scanning means for receiving reflected energy;

15 c) moving the energy relative to said substrate such that said energy is in focus at an initial or base focal plane below the upper surface of said substrate and substantially parallel thereto, relative to said scanning means;

d) generating a signal in response to said reflected energy, said signal adapted to vary with the intensity thereof;

20 e) correlating said signal to a reference level of intensity representative of surface reflectivity;

f) moving said energy relative to said substrate such that said energy is in focus at a plane above said initial focal plane and substantially parallel thereto;

25 g) repeating steps (d) through (f) until the focused plane is above the level of the upper surface of said circuit feature; and

h) correlating said signals generated in step (e) to measurements representative of the height of said circuit features and any printed circuit wiring defects.

13. The method in accordance with claim 12, further comprising the step of storing a reflected energy value representative of the location of the focused plane relative to said initial focal plane for each plane scanned thereby.
- 5 14. The method in accordance with claim 13, further comprising the step of subtracting the value representative of the focal plane at the upper surface of said substrate from the value representative of the focal plane at the upper surface of said circuit feature to obtain a value representative of the height of the upper surface thereof
10 relative to said upper substrate surface.

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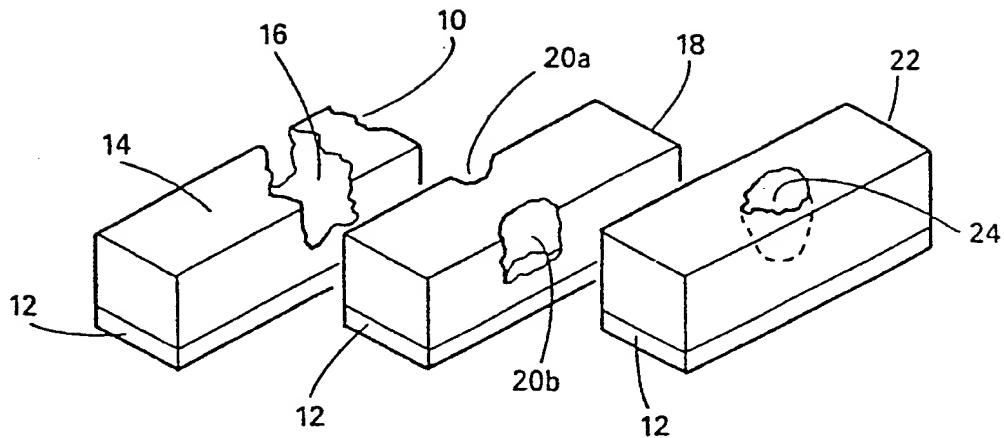


FIGURE 1

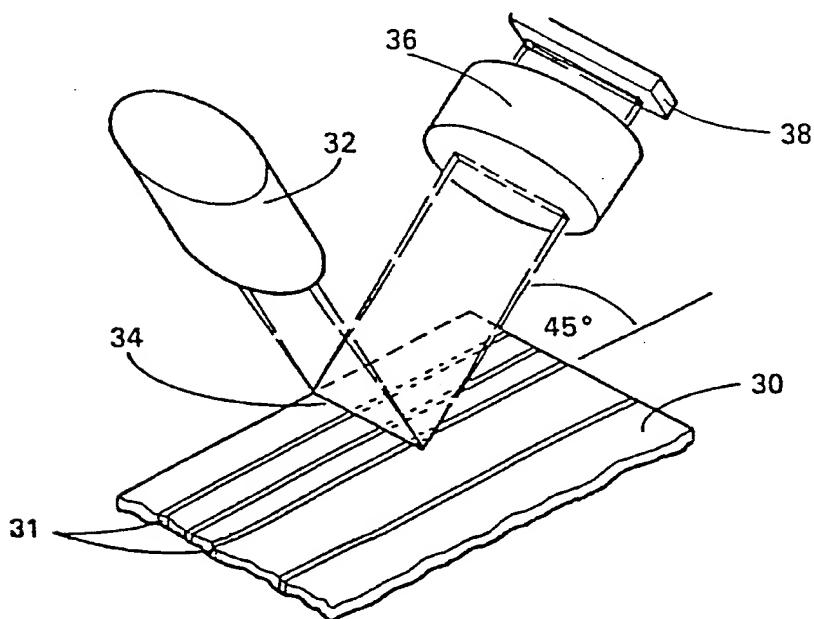
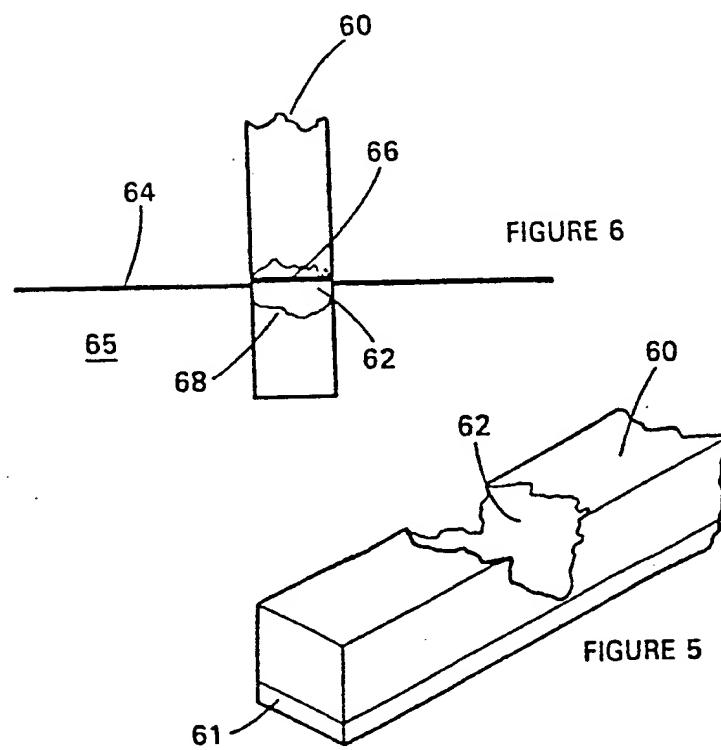
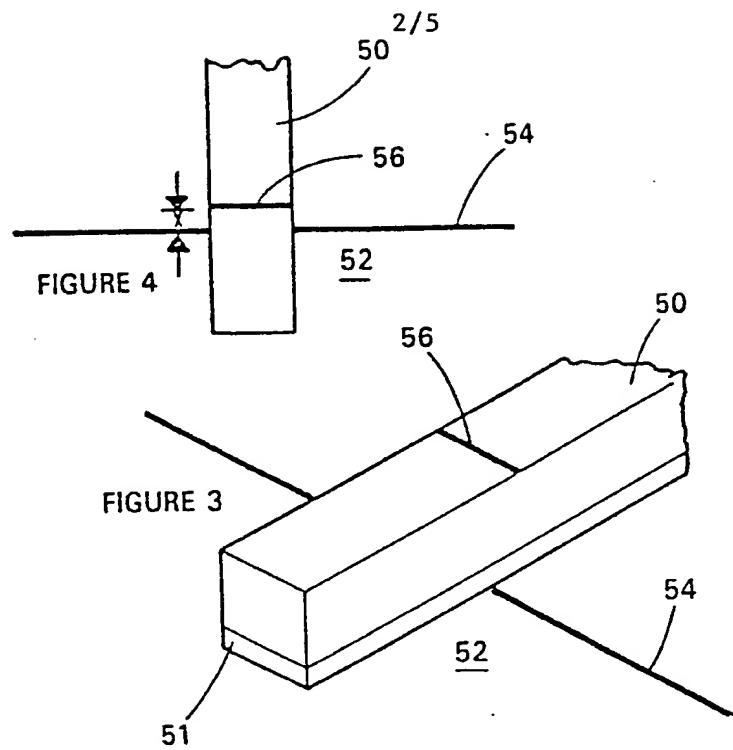


FIGURE 2

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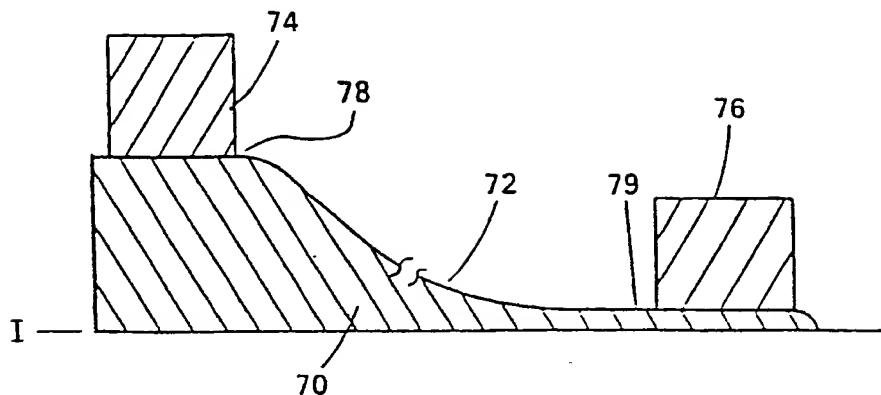


FIGURE 7

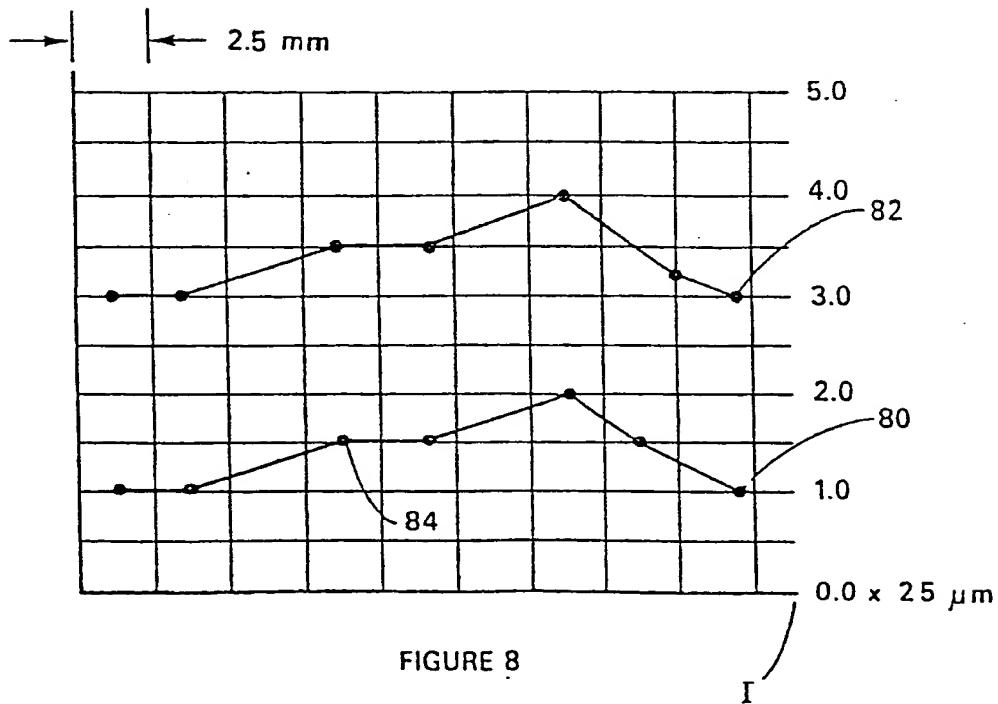


FIGURE 8

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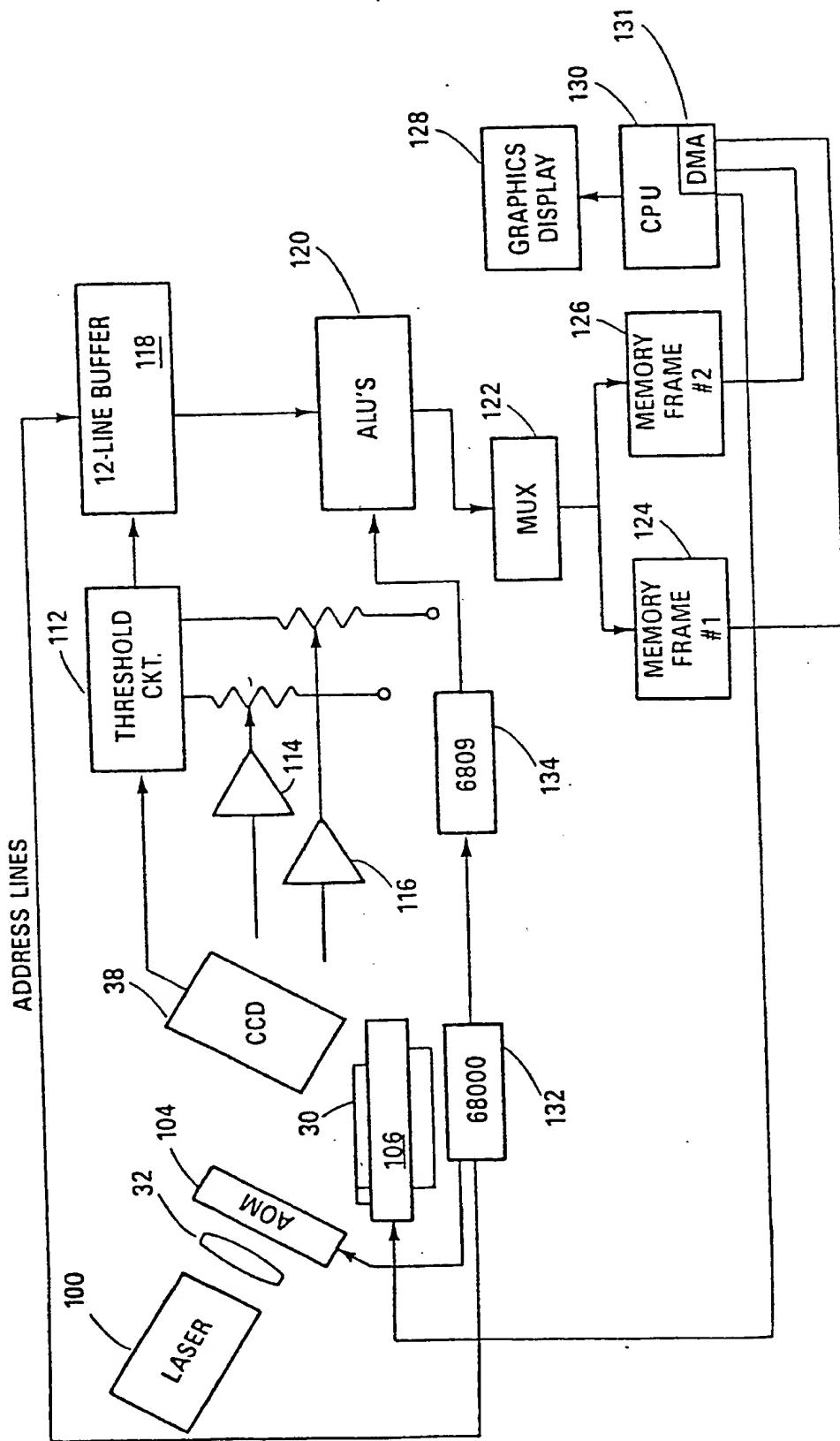
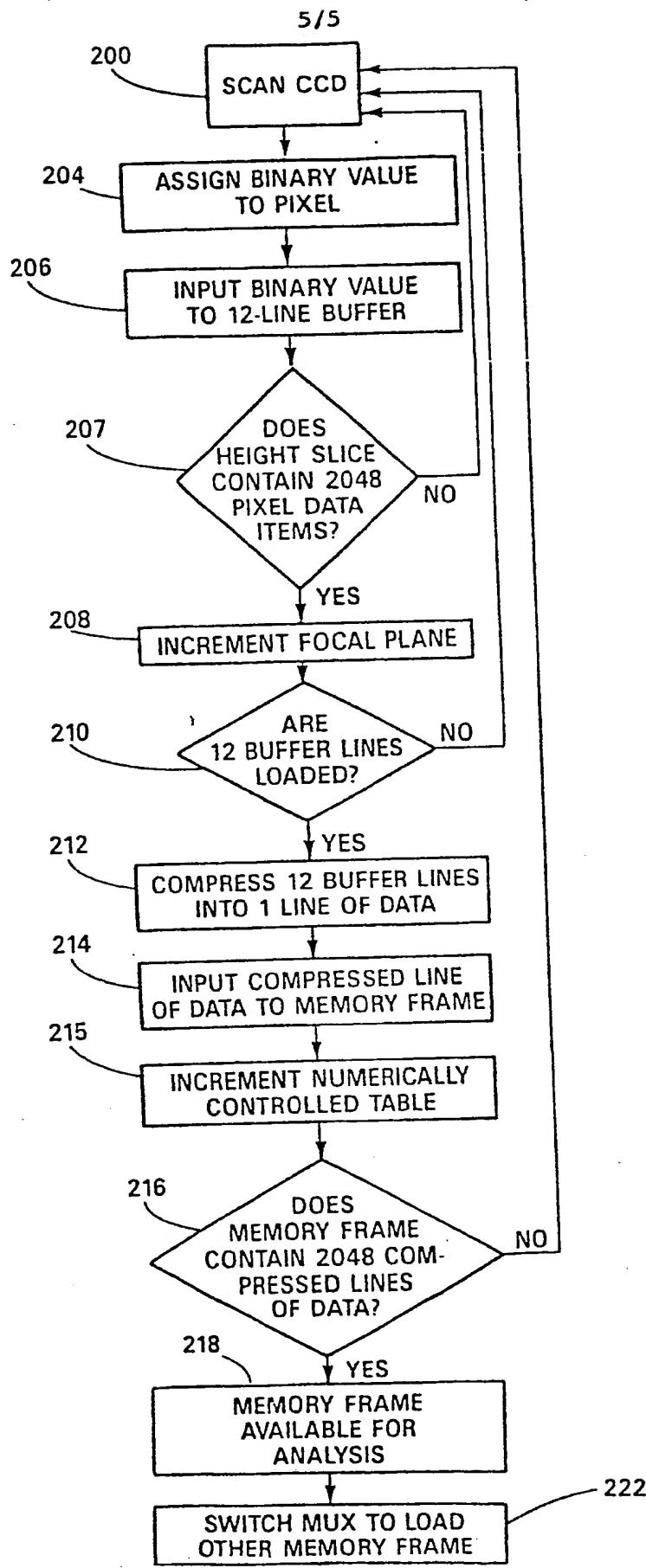


FIGURE 9

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EUROPEAN SEARCH REPORT

0160781

Application number

EP 85 10 1039

DOCUMENTS CONSIDERED TO BE RELEVANT

Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int. Cl.4)
Y	IBM TECHNICAL DISCLOSURE BULLETIN, vol. 21, no. 2, July 1978; P.S. HAUGE "Optical film thickness measurement tool", pages 884-885 * Whole document *	1-5, 7-10	G 01 B 11/24 G 01 R 31/28
Y	--- DE-A-2 554 086 (IBM) * Claims 1, 8-10; figure 1 *	1-5, 7-10	
A	---	6, 12, 14	
A	--- US-A-4 343 553 (Y. NAKAGAWA et al.) * Abstract; figure 1 *	1	TECHNICAL FIELDS SEARCHED (Int. Cl.4)
D, A	--- EP-A-0 085 868 (IBM) * Abstract; figures 1, 2 *	1	G 01 B 11/02 G 01 B 11/06 G 01 B 11/24 G 01 B 11/30 G 01 R 31/28
D, A	--- IBM TECHNICAL DISCLOSURE BULLETIN, vol. 14, no. 12, May 1972; S.H. CAMPBELL et al. "Noncontact test system", pages 3621-3622 * Whole document *	1	

The present search report has been drawn up for all claims			
Place of search	Date of completion of the search	Examiner	
BERLIN	12-07-1985	LEMMERICH J	

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